NSN 5961-00-419-5362

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-419-5362 **Inclosure Material:** Metal **Overall Length:** Between 0.235 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-77 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -30.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 25.00 milliamperes drain current all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0